



Normal Capacitance ESD Protector

Description

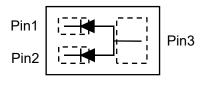
The PESDNC3FD10VU is a Transient Voltage Suppressor Arrays that designed to protect components which are connected to data and transmission lines against electrostatic discharge(ESD), electrical fast transients(EFT), and lightning.

All pins are rated to withstand 30kV ESD pulses using the IEC61000-4-2 air discharge method.

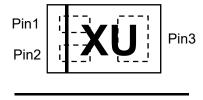
DFN1006-3L(Bottom View)

Feature

- \triangleright 233W peak pulse power per line (t_P = 8/20 μ s)
- ➤ DFN1006-3L package
- > Response time is typically < 1 ns
- Unidirectional configurations
- > Low clamping voltage
- > RoHS compliant
- ➤ Transient protection for data lines to IEC 61000-4-2(ESD) ±30kV(air), ± 30kV(contact); IEC 61000-4-5 (Lightning) 11A (8/20us)



Circuit Diagram



Marking (Top View)

Applications

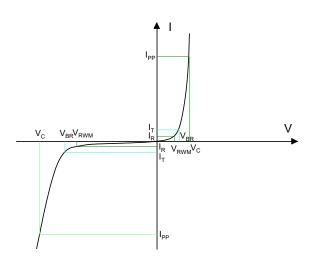
- > Cell phone handsets and accessories
- Personal digital assistants (PDA's)
- Notebooks, desktops, and servers
- Portable instrumentation
- Cordless phones
- Digital cameras
- > Peripherals

Mechanical Characteristics

- Mounting position: Any
- Qualified max reflow temperature:260°C
- > DFN1006-3L without plating

Electronics Parameter

Symbol	Parameter			
V_{RWM}	Peak Reverse Working Voltage			
I _R	Reverse Leakage Current @ V _{RWM}			
V_{BR}	Breakdown Voltage @ I _T			
I _T	Test Current			
I _{PP}	Maximum Reverse Peak Pulse Current			
V _C	Clamping Voltage @ I _{PP}			
P _{PP}	Peak Pulse Power			
CJ	Junction Capacitance			
I _F	Forward Current			
V_{F}	Forward Voltage @ I _F			



Electrical characteristics per line@25°C (unless otherwise specified)

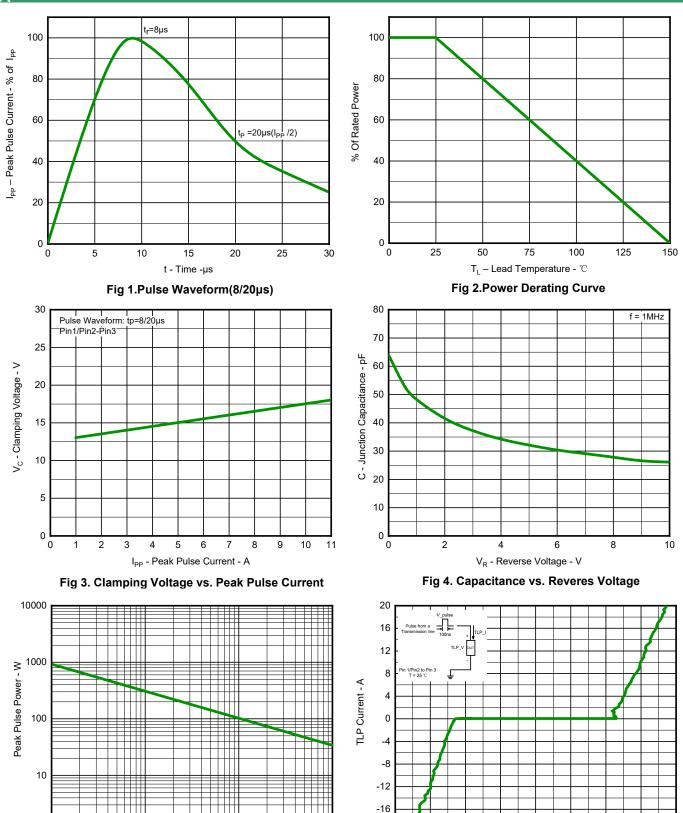
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Peak Reverse Working Voltage	V_{RWM}	-	-	-	10	V
Breakdown Voltage	V_{BR}	I _t = 1mA	11	-	13	V
Reverse Leakage Current	I _R	V _{RWM} = 10V	-	-	100	nA
Clamping Voltage ¹⁾	V _C	TLP = 16A, $t_p = 100 \text{ns}$	-	16	-	V
Dynamic resistance ¹⁾	R _{DYN}	-	-	0.2	-	Ω
Clamping Voltage ²⁾	V _C	$I_{PP} = 1A$, $t_{P} = 8/20 \mu s$, Pin1/Pin2 to Pin3	-	-	14	V
		$I_{PP} = 11A$, $t_{P} = 8/20\mu s$, Pin1/Pin2 to Pin3	-	18	20	V
Junction Capacitance	CJ	$V_R = 0V, f = 1MHz$	-	66	80	pF

Absolute maximum rating@25°C

Rating	Symbol	Value	Units
Peak Pulse Power (t _P = 8/20µs)	P _{PP}	233	W
Peak Pulse Current (t _P = 8/20μs)	I _{PP}	11	А
Lead Soldering Temperature	T _L	260 (10 sec)	°C
Junction and Storage Temperature Range	$T_{J,}T_{STG}$	-55~+150	°C
ESD Protection-Contact Discharge	V _{ESD}	±30	kV
ESD Protection-Air Discharge	V _{ESD}	±30	kV

^{1.}TLP parameter: Z_0 =50 Ω , t_p =100ns, t_r =2ns, averaging window from 70ns to 90ns. R_{DYN} is calculated from 4A to 16A. 2.Non-repetitive current pulse, according to IEC61000-4-5.

Typical Characteristics



 $\label{eq:Pulse Duration - } \mu s$ Fig 5. Non Repetitive Peak Pulse Power vs. Pulse Time

100

10

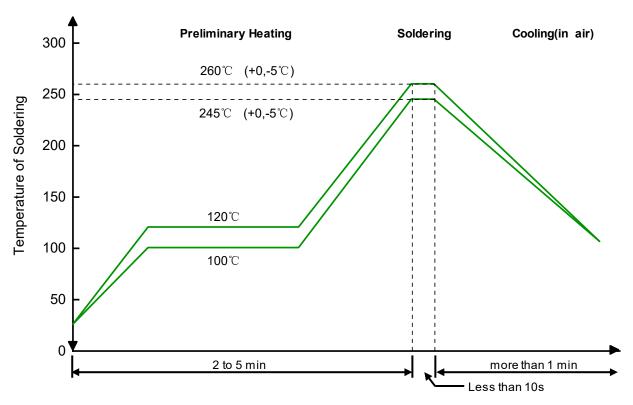
TLP Voltage - V Fig 6. TLP Measurement

15

1000

-20

Solder Reflow Recommendation



Remark: Pb free for 260°C; Pb for 245°C.

PCB Design

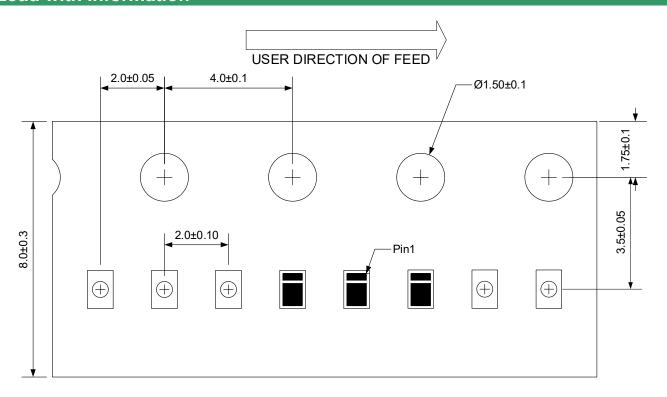
For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

- > Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- > Do not make false economies and save copper for the ground connection.
- Place via holes to ground as close as possible to the anode of the TVS diode.
- Use as many via holes as possible for the ground connection.
- ➤ Keep the length of via holes in mind! The longer the more inductance they will have.

Ordering information

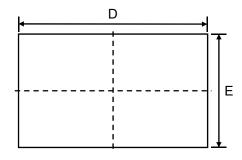
Device	Package	Reel	Shipping
PESDNC3FD10VU	DFN1006-3L	7"	10000 / Tape & Reel

Load with information

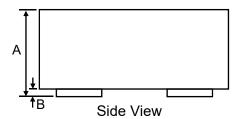


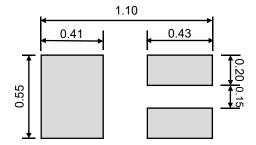
Unit:mm

Product dimension (DFN1006-3L)

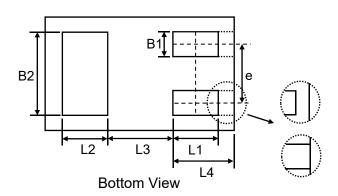


Top View





Suggested PCB Layout



Dim	Millimeters		Inches		
Dilli	Min	Max	Min	Max	
А	0.33	0.55	0.013	0.022	
В	0.00	0.05	0.000	0.002	
B1	0.10	0.20	0.004	0.008	
B2	0.45	0.55	0.018	0.022	
D	0.90	1.05	0.035	0.041	
E	0.50	0.65	0.020	0.026	
е	0.35		0.014		
L1	0.20	0.30	0.008	0.012	
L2	0.20	0.30	0.008	0.012	
L3	0.39		0.015		
L4	0.25	0.35	0.010	0.014	

Unit: mm

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